

Optically Immersed 2.8 μm LED in heatsink optimized housing

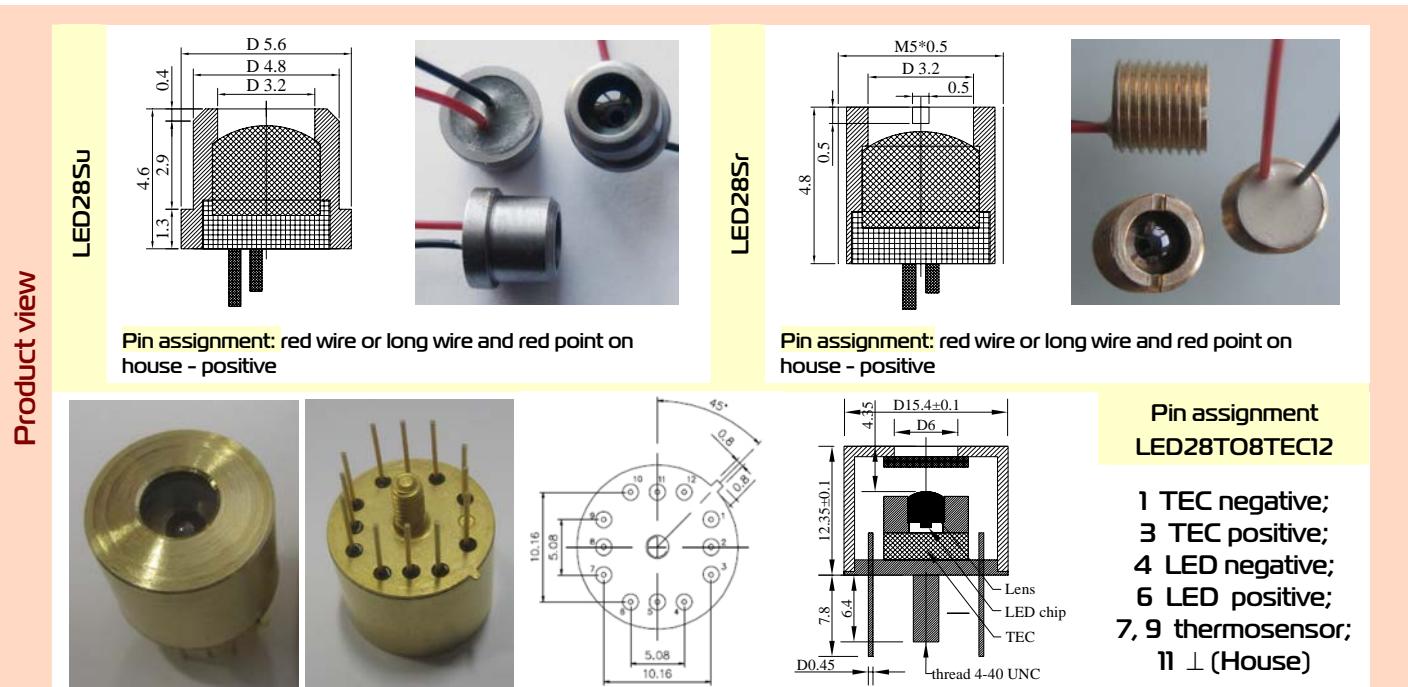
LED28Su, LED28Sr

TE cooled Optically Immersed 2.8 μm LED

LED28TO8TEC

Peak wavelength	μm	2.83\pm0.03 ¹
Pulse power	mW	Drive current 1 A, 0.02 duty cycle 0.15\pm0.18
Quasi-CW power	mW	Drive current 0.3 A, 0.5 duty cycle 0.05\pm0.06
CW power	mW	Drive current 0.2 A 0.03\pm0.04
Cut-off frequency	MHz	20 ²

Code	Emission size, mm	Weight, g	Optical components	Far-field pattern FWHM, deg.	Optical axis deviation, deg.	Optical power deviation in lot, %	Operation conditions, $^{\circ}\text{C}$	Lifetime, hrs
LED28Su			Si lens				-60 \div +120 ³	
LED28Sr	\varnothing 3.2	\sim 0.4	Si lens	\sim 15	\leq 5	\pm 25		$>80\,000$ ⁵
LED28TO8TEC		\sim 10	Si lens and output sapphire window D=6mm				-60 \div +85 ⁴	



Features

- Original growth of narrow gap semiconductor alloys onto n^{+} -InAs substrate;
- Flip-chip design of LEDs;
- Optical coupling through the use of chalcogenide glasses and Si lenses with antireflection coating

- 3-fold increased LED output power;
- Beam collimation;
- Small on-off time (tenths of ns);
- Low power consumption (\leq 0.1 W)

Emission beam divergence is small and thus we recommend adjusting LED position regarding to the detector system before final evaluation/use of the devices. We recommend if possible using low duty cycle mode of operation with $I < 0.5 \times I_{max}$ so that higher efficiency and long term stability of a LED are achieved. Data are valid for LED attached to a heatsink and thermostabilized at 22°C. Heatsink is essential for TEC operation!

¹ - process 296
² - according to estimation
³ - devices have passed through 15 thermo cycles : (20°C, 8 hrs) - transition period of 30 min - (+125°C, 8 hrs) without changes in specifications. Valid for devices produced since 01.2013
⁴ - devices have passed through 15 thermo cycles : (-60°C, 30 min) - transition period of 30 min -(+85°C, 30 min) without changes in specifications. Valid for devices produced since 01.2013
⁵ - according to accelerated degradation stress at CW drive current 0.2 A

Product specifications are subject to change without prior notice due to improvements or other reasons. Updated 15.01.13

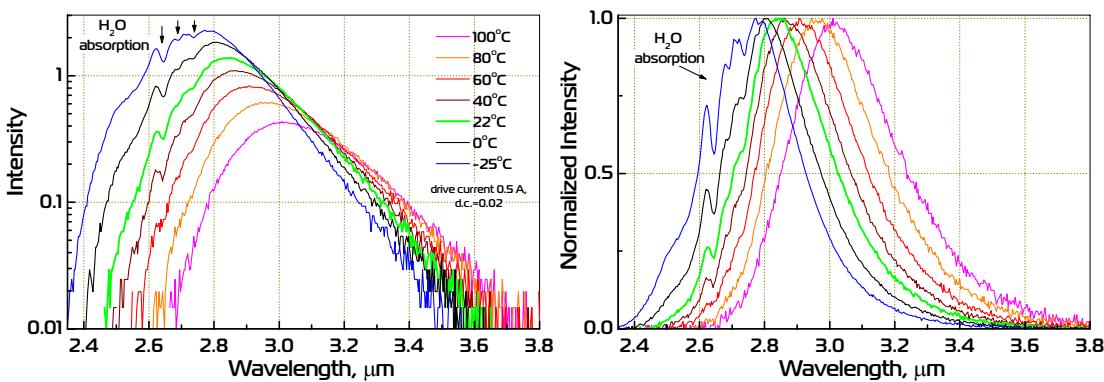


ООО «ИоффеLED»
IoffeLED, Ltd

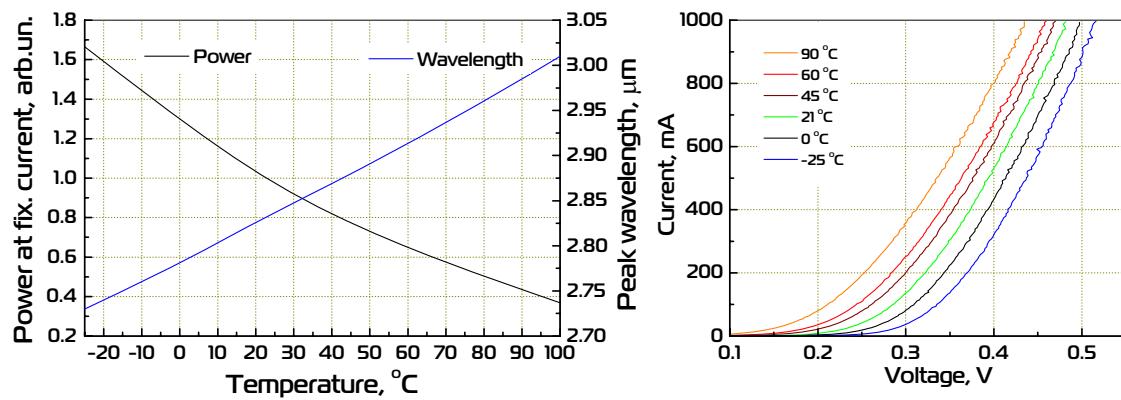
Politehnicheskaya 26,
St.Petersburg, 194021, RUSSIA

<http://www.ioffeled.com>; e-mail: Mremennyy@mail.ioffe.ru
<http://www.mirdog.spb.ru>; e-mail: brmat@iropt3.ioffe.ru

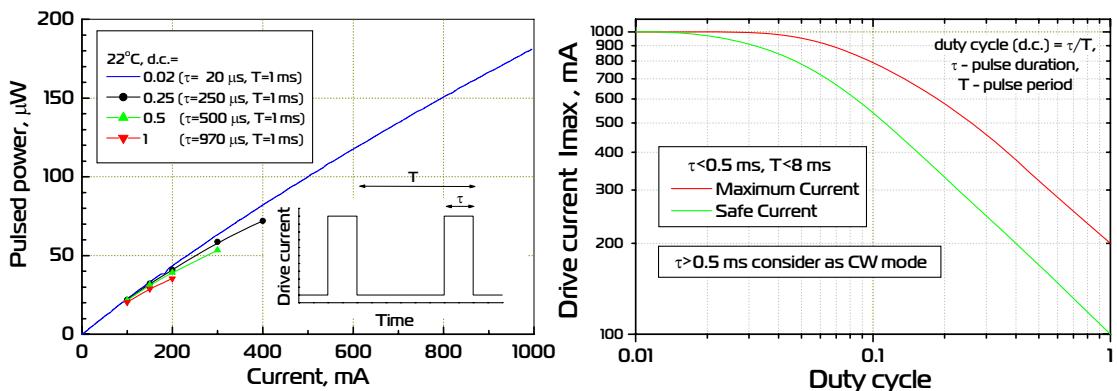
Emission spectra



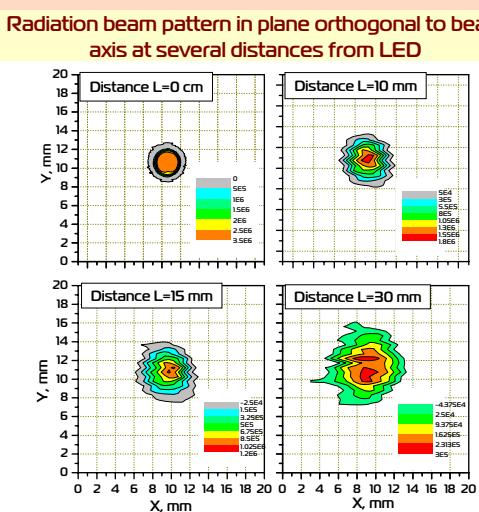
Power and peak wavelength vs. temperature; I – V curve



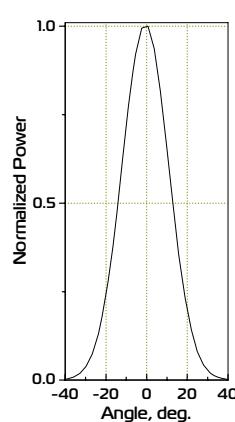
Output power and drive current vs operation conditions



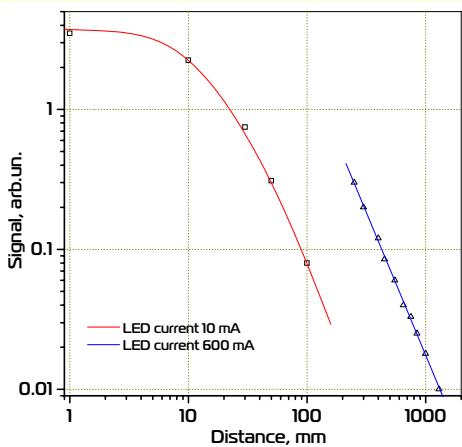
Far-field characterization



Angle distribution of output power



PD signal (PDxxSr/Su) vs. distance from activated LED



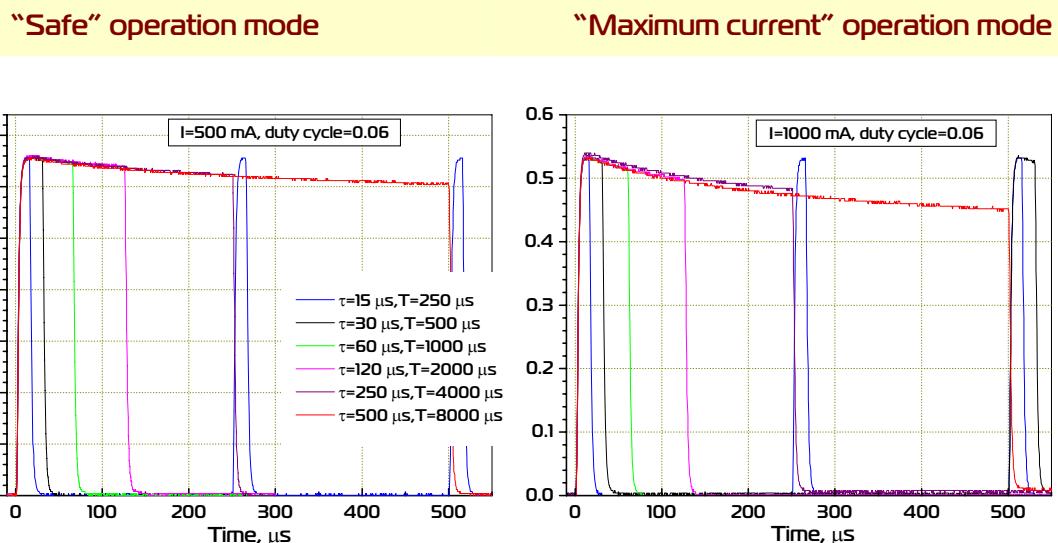
ООО «ИоффеLED»
IoffeLED, Ltd

Politehnicheskaya 26,
St.Petersburg, 194021, RUSSIA

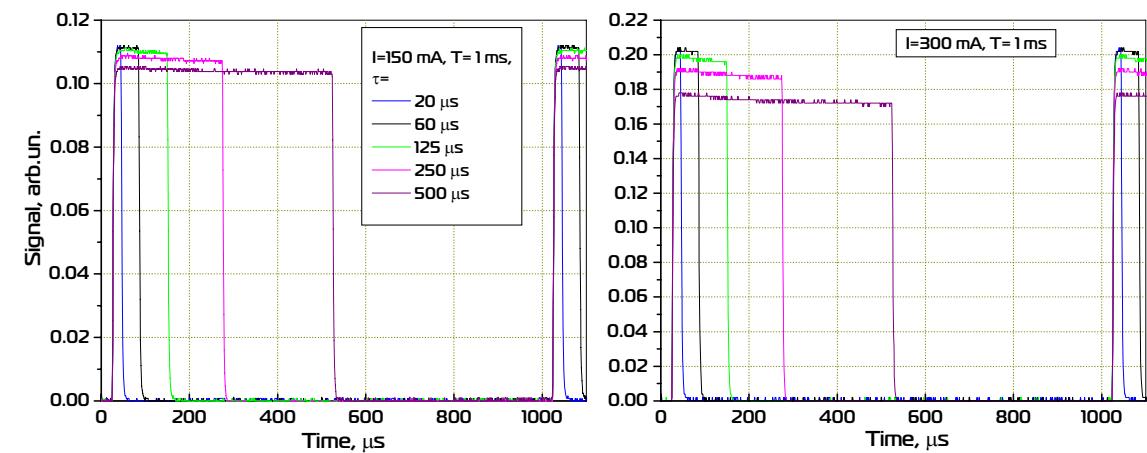
<http://www.ioffeled.com>; e-mail: Mremennyy@mail.ioffe.ru
<http://www.mirdog.spb.ru>; e-mail: bmat@iropt3.ioffe.ru

Time dependence of the output power for several values of d.c. and currents
 (LED attached to a heatsink at room temperature).

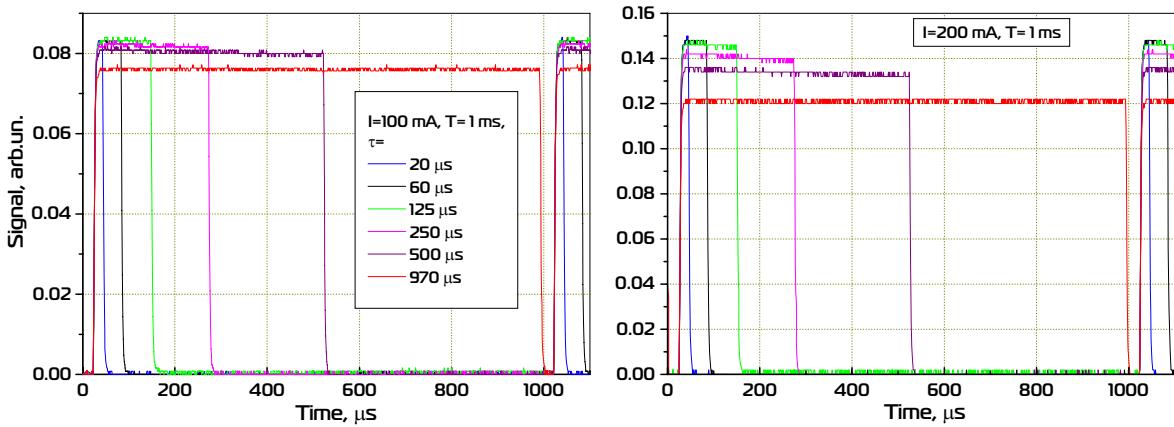
Pulse operation (d.c.=0.06)



Quasi CW mode (d.c.=0.5)



CW mode (d.c.=1)

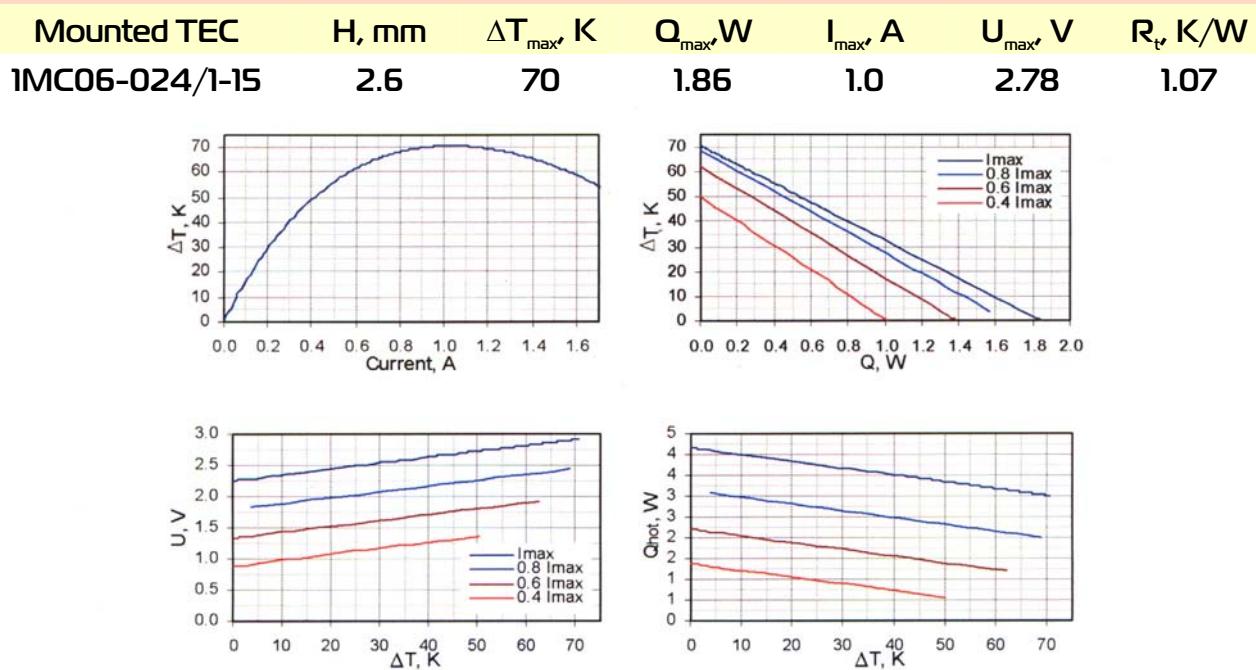


ООО «ИоффеLED»
 IoffeLED, Ltd

Politehnicheskaya 26,
 St.Petersburg, 194021, RUSSIA

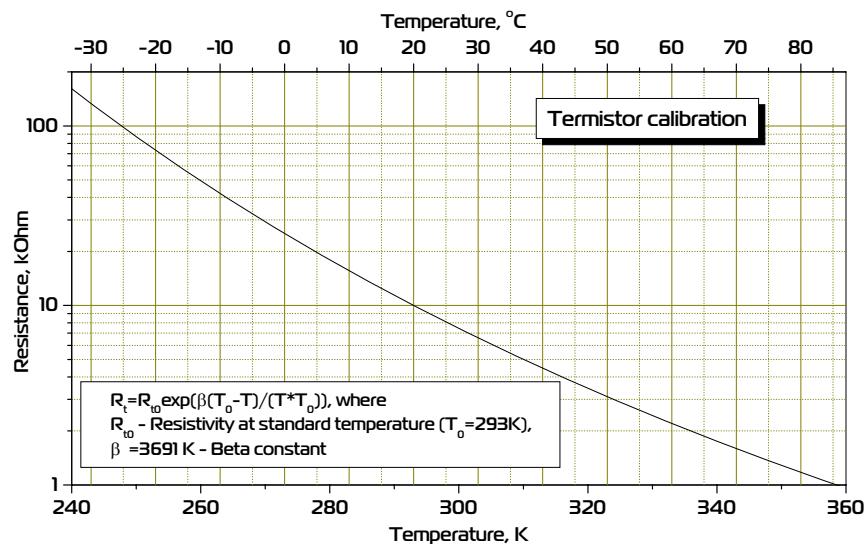
<http://www.ioffeled.com>; e-mail: Mremennyy@mail.ioffe.ru
<http://www.mirdog.spb.ru>; e-mail: bmat@iropt3.ioffe.ru

Thermoelectric cooling module datasheet



Thermistor specification

T, °C	R, kΩ	T, °C	R, kΩ
-60	1134.5	15	12.44
-55	762.4	20	10.00
-50	521.6	25	8.09
-45	362.8	25	8.09
-40	256.3	30	6.60
-35	183.8	35	5.41
-30	133.6	40	4.47
-25	98.3	45	3.71
-20	73.3	50	3.10
-15	55.2	55	2.61
-10	42.1	60	2.20
-5	32.4	65	1.87
0	25.2	70	1.59
5	19.7	75	1.37
10	15.6	80	1.18



Possible TEC heatsink view



ООО «ИоффеLED»
IoffeLED, Ltd

Politehnicheskaya 26,
St.Petersburg, 194021, RUSSIA

<http://www.ioffeled.com>; e-mail: Mremennyy@mail.ioffe.ru
<http://www.mirdog.spb.ru>; e-mail: bmat@iropt3.ioffe.ru